

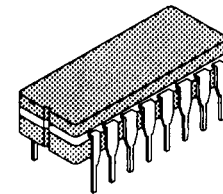
# MB810A / 811A / 812A / 813A / 814A

## Ultra High-Speed ECL ICs

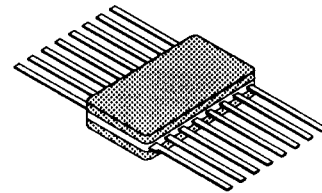
### Ultra High-speed ECL Family

The Fujitsu MB810A series is an ultra high-speed logic designed for high-speed digital systems. The MB810A series is suitable for use in high-speed transmission equipment, radio installations, high-speed logic treatment equipment, high-performance measuring instruments, and high-speed gate array peripherals. The input and output levels and the power supply voltage are compatible with the ECL 10KH Series. The devices are housed in ceramic 16-pin small outline and dual-in-line packages.

- Ultra high-speed:  
Propagation delay time – 400 ps/gate typical
- ECL Interface level:  
10KH ECL compatible inputs and outputs
- Output rising/falling time – 350 ps typical
- Maximum clock frequency: 1.5 GHz typical
- Emitter Follower Output: Wired OR capability, 50  $\Omega$  line drive capability
- Stable bias circuit for the changeable power supply voltage
- Ceramic 16-pin packages:  
DIP MB81xAC  
SOP MB81xAZF



Ceramic DIP Package  
DIP-16C-C01



Ceramic SOP Package  
FPT-16C-C01

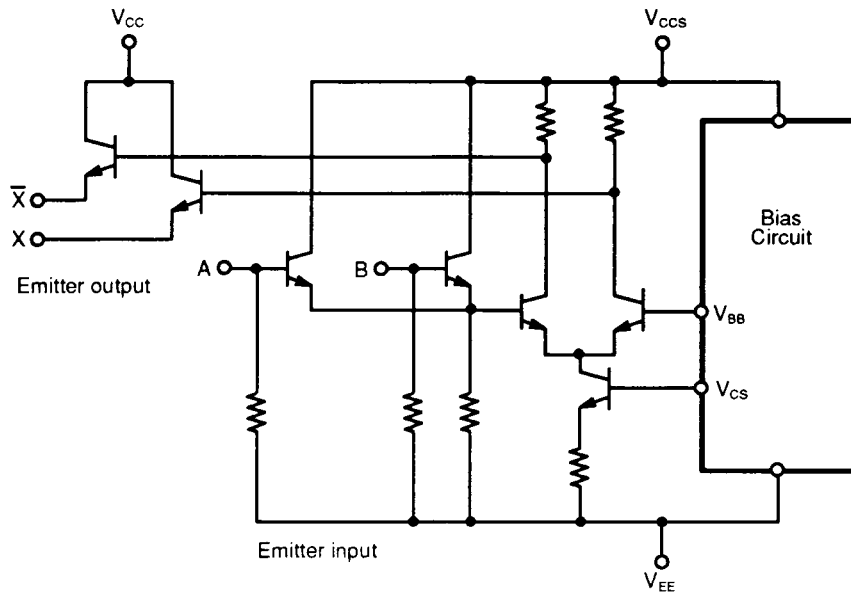
### ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Ratings	Unit
Power Supply Voltage ( $V_{CCS} = V_{CCF} = 0$ )	$V_{EE}$	-7.0 to 0	V
Input Voltage ( $V_{CCS} = V_{CCF} = 0$ )	$V_{IN}$	-3.0 to 0	V
Output Current	$I_{OUT}$	-50 to 0	mA
Operating Ambient Temperature	$T_A$	-30 to +125	$^{\circ}\text{C}$
Storage Temperature	$T_{STG}$	-55 to +150	$^{\circ}\text{C}$

**Note:** Permanent device damage may occur if absolute maximum ratings are exceeded. Functional operation should be restricted to the conditions as detailed in the operation sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields. However, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit.

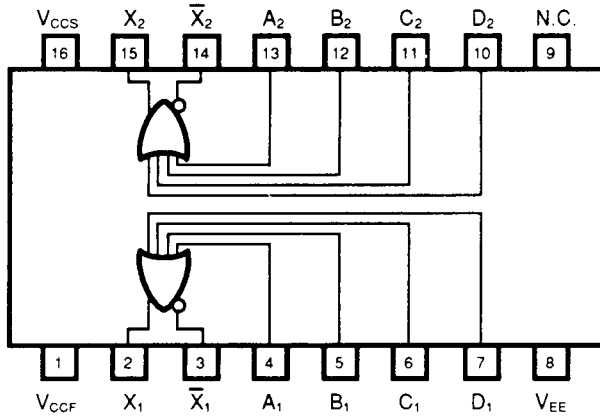
**Fig.1 – MB810A SERIES BASIC GATE CIRCUIT**



## PIN ASSIGNMENTS

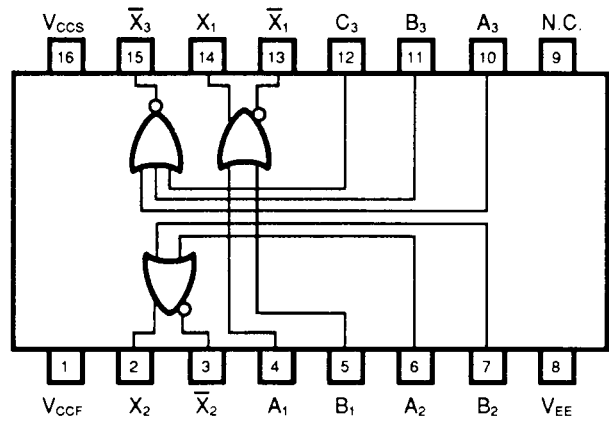
**MB810A – Dual 4-Input OR/NOR Gate**

$$X = A+B+C+D \quad \bar{X} = \overline{A+B+C+D}$$



Input				Output	
A	B	C	D	X	$\bar{X}$
H	X	X	X	H	L
X	H	X	X	H	L
X	X	H	X	H	L
X	X	X	H	H	L
L	L	L	L	L	H

**MB811A – Triple 2-2-3-Input OR/NOR Gate**



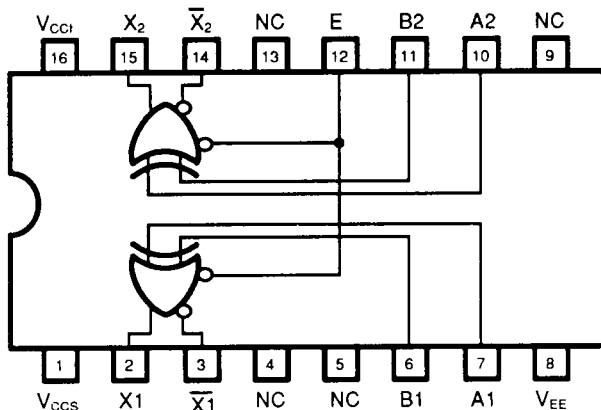
Input		Output	
A	B	X	$\bar{X}$
H	X	H	L
X	H	H	L
L	L	L	H

Input			Output
A	B	C	$\bar{X}$
H	X	X	L
X	H	X	L
X	X	H	L
L	L	L	H

## PIN ASSIGNMENTS (Continued)

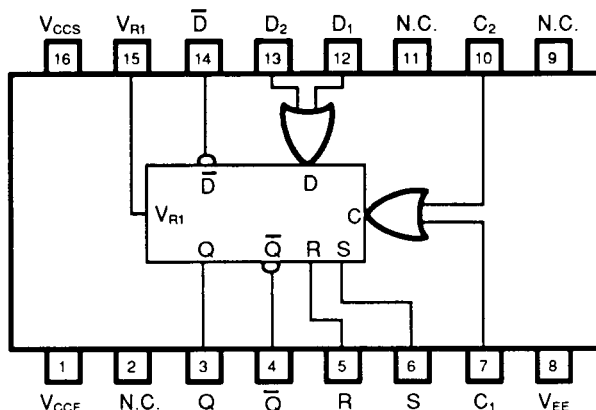
**MB812A – Dual Exclusive OR/NOR Gate**

$$X = A\bar{B} + \bar{A}B \quad \bar{X} = A\bar{B} + \bar{A}\bar{B}$$



Input			Output	
A	B	$\bar{E}$	X	$\bar{X}$
H	H	L	L	H
L	H	L	H	L
H	L	L	H	L
L	L	L	L	H
X	X	H	L	H

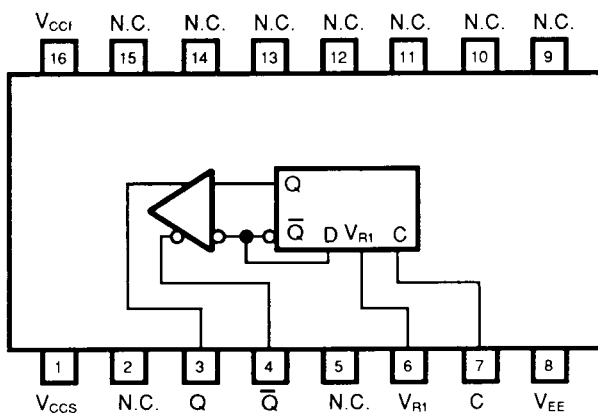
**MB813A – 2-Input D-Type Flip-Flop with Set and Reset**



Input				Output	
Set	Reset	Clock	D	Q	$\bar{Q}$
H	H	X	X	*	*
H	L	X	X	H	L
L	H	X	X	L	H
L	L	↑	H	H	L
L	L	↑	L	L	H
L	L	L	X	$Q_0$	$\bar{Q}_0$

D: Complement input of D.  
 If D only is used,  $\bar{D}$  must be connected to  $V_{R1}$  externally.

**MB814A – T-Type Flip-Flop**



Input	Output	
C	$Q_{n+1}$	$\bar{Q}_{n+1}$
L	$Q_n$	$Q_n$
↑	$\bar{Q}_n$	$Q_n$

**Notes:**

- H :High
- L :Low
- X :Don't Care
- ↑ :L to H transition
- \* :Irrelevant
- $Q_0$  :The level before establishment of Input condition
- $\bar{Q}_0$  :Complementary output of  $Q_0$
- $Q_n$  :Before adding clock
- $Q_{n+1}$  :After adding clock

MB810A  
 MB811A  
 MB812A  
 MB813A  
 MB814A

## RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Value	Unit
Power Supply ( $V_{CCS} = V_{CCF} = 0$ )	$V_{EE}$	$-5.2 \pm 5\%$	V
Terminal Voltage	$V_T$	$2.0 \pm 5\%*$	V
Operating Ambient Temperature	$T_A$	0 to +75	°C

Note: \*Each output is terminated through a 50  $\Omega$  resistor.

## DC CHARACTERISTICS

(Recommended operating conditions otherwise noted.  $V_{CCS} = V_{CCF} = 0V$ ,  $R_T = 50\Omega$ ) ( $T_A = 0^\circ C$  to  $+75^\circ C$ )

Parameter	Conditions	Symbol	Value			Unit
			Min	Typ	Max	
High-level Output Voltage	$V_{IH} = -0.73V$	$V_{OH}$	-1.02	-0.90	-0.73	V
Low-level Output Voltage	$V_{IL} = -1.87V$	$V_{OL}$	-1.87	-1.75	-1.60	V
High-level Threshold Voltage	$V_{IH} = -1.07V$	$V_{OHA}$	-1.02			V
Low-level Threshold Voltage	$V_{IL} = -1.48V$	$V_{OLA}$			-1.60	V
Input Current	$V_{IH} = -0.73V$	MB810A, MB811A		0.12	0.21	mA
		MB812A		0.12	0.19	mA
		MB813A		0.15	0.28	mA
		MB814A		0.13	0.25	mA
Power Supply Current	MB811A, MB812A, MB813A	$I_{EE}$	-35	-26	-15	mA
	MB810A		-25	-19	-10	mA
	MB814A		-28	-21	-15	mA
Reference Voltage	MB813A, MB814A	$V_{R1}$	-1.38	-1.29	-1.18	V

## AC CHARACTERISTICS

(MB810A, MB811A, MB812A)

(T<sub>A</sub> = +25°C)

Parameter	Condition	Symbol	Value			Unit
			Min	Typ	Max	
Propagation Delay Time	$V_{CCS} = V_{CCF} = +2.0V$ $R_T = 50\Omega$ $V_{EE} = -3.2V$ $V_T = \text{Ground}$ Input Pulse $t_r = t_f \leq 500ps$ $V_{IH} = +1.1V$ $V_{IL} = +0.3V$ PRR = 100MHz	t <sub>PLH</sub>		400	650	ps
		t <sub>PHL</sub>		400	650	ps
Rising Time (20% to 80%)		t <sub>TLH</sub>		350	550	ps
Falling Time (80% to 20%)		t <sub>THL</sub>		350	550	ps

## AC CHARACTERISTICS

(MB813A)

(T<sub>A</sub> = +25°C)

Parameter	Condition	Symbol	Value			Unit
			Min	Typ	Max	
Propagation Delay Time (Clock, Reset and Set to output)	$V_{CCS} = V_{CCF} = +2.0V$ $R_T = 50\Omega$ $V_{EE} = -3.2V$ $V_T = \text{Ground}$ Input Pulse $t_r = t_f \leq 500ps$ $V_{IH} = +1.1V$ $V_{IL} = +0.3V$ PRR = 100MHz	t <sub>PLH</sub>		900	1200	ps
		t <sub>PHL</sub>		900	1200	ps
Rising Time (20% to 80%)		t <sub>TLH</sub>		350	550	ps
Falling Time (80% to 20%)		t <sub>THL</sub>		350	550	ps
Setup Time		t <sub>set</sub>	500	250		ps
Hold Time		t <sub>hold</sub>	500	250		ps
Clock Frequency		t <sub>log</sub>	1.0	1.5		GHz

## AC CHARACTERISTICS

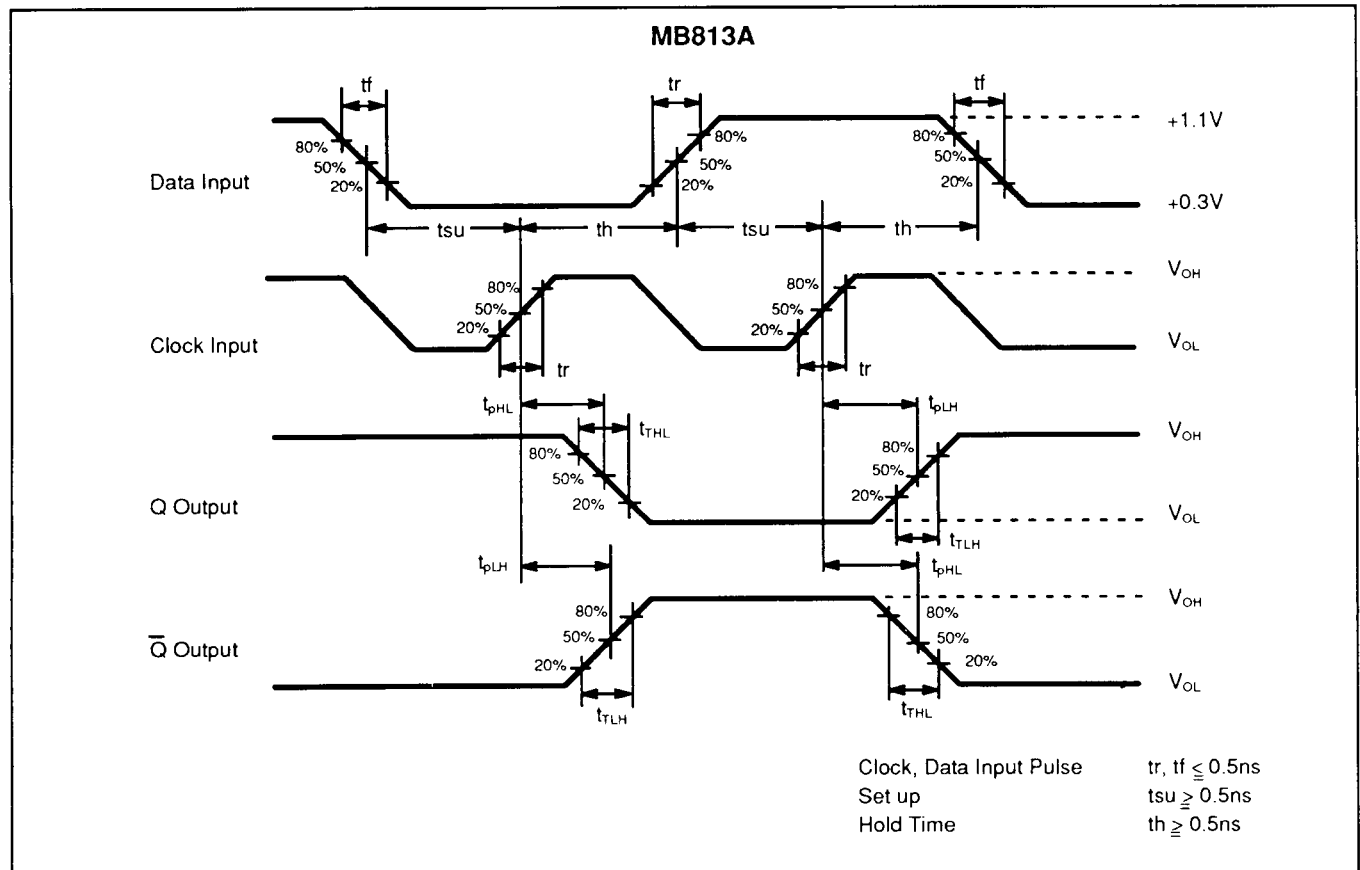
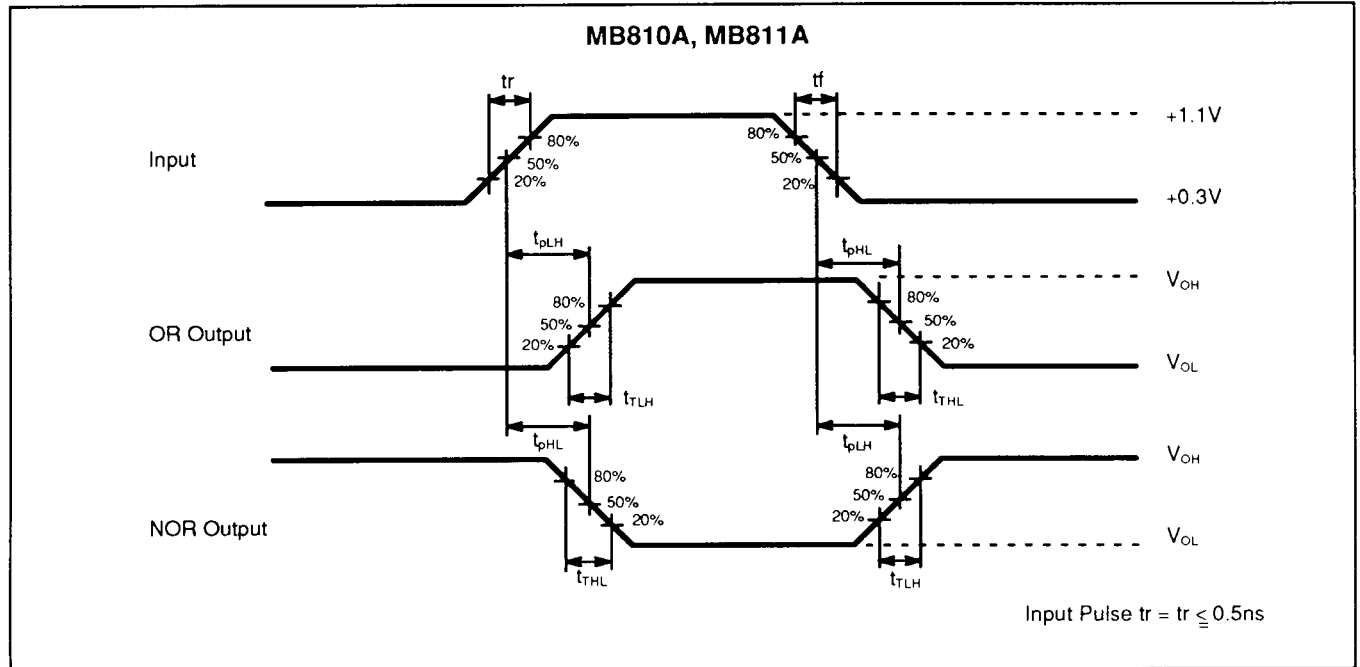
(MB814A)

(T<sub>A</sub> = +25°C)

Parameter	Condition	Symbol	Value			Unit
			Min	Typ	Max	
Propagation Delay Time	$V_{CCS} = V_{CCF} = +2.0V$ $R_T = 50\Omega$ $V_{EE} = -3.2V$ $V_T = \text{Ground}$ Input Pulse $t_r = t_f \leq 500ps$ $V_{IH} = +1.1V$ $V_{IL} = +0.3V$ PRR = 100MHz	t <sub>PLH</sub>	500	900	1200	ps
		t <sub>PHL</sub>	500	900	1200	ps
Rising Time (20% to 80%)		t <sub>TLH</sub>		350	550	ps
Falling Time (80% to 20%)		t <sub>THL</sub>		350	550	ps
Clock Frequency		t <sub>log</sub>	1.3	1.5		GHz

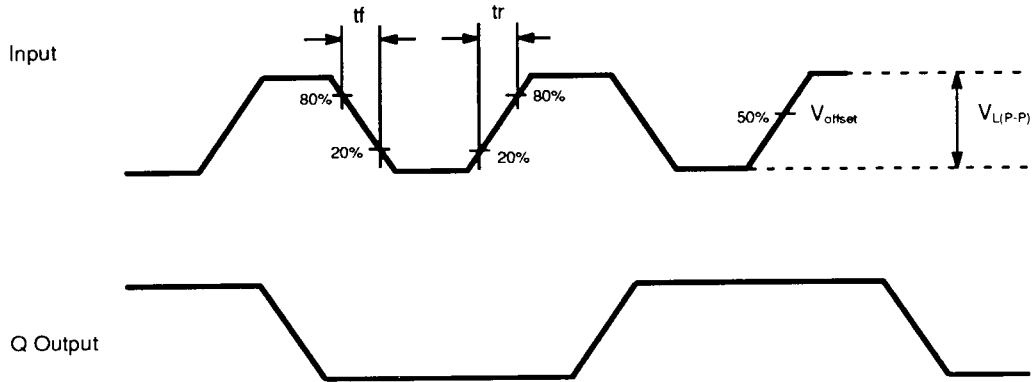
# SWITCHING WAVE FORM

## INPUT/OUTPUT WAVE FORM



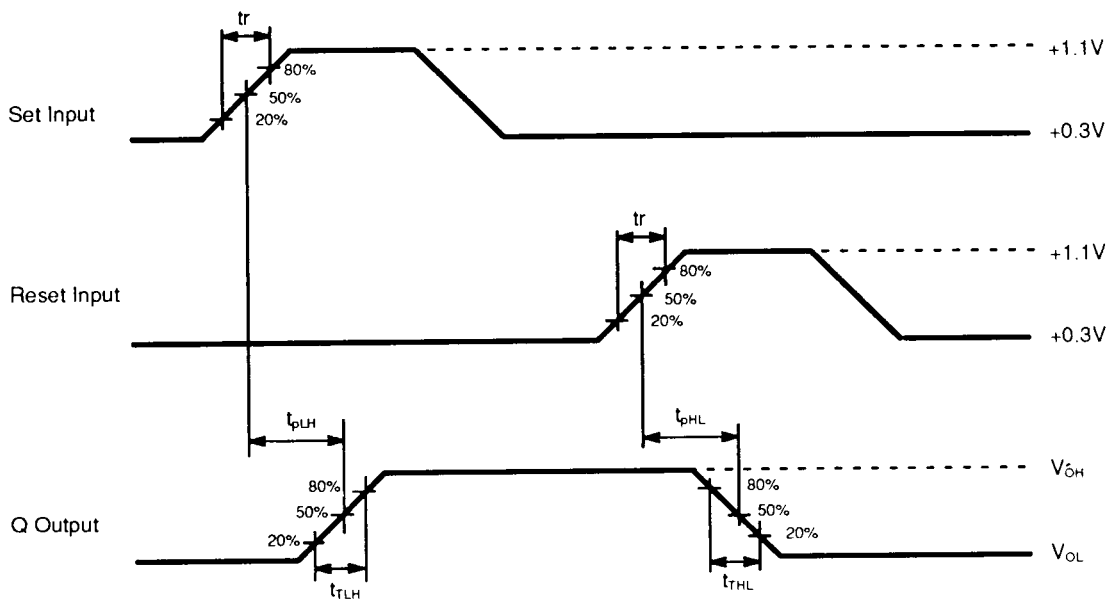
## SWITCHING WAVE FORM (Continued)

**TOGGLE WAVE FORM**  
 MB813A, MB814A



Q output PRR is 1/2PRR of Input  
 1/2PRR Input Duty Cycle = 50%  
 $t_r, t_f \leq 500\text{ps}$   
 $V_{\text{offset}} = +0.7\text{V}$   
 $V_{L(P-P)} = 800\text{mV}$

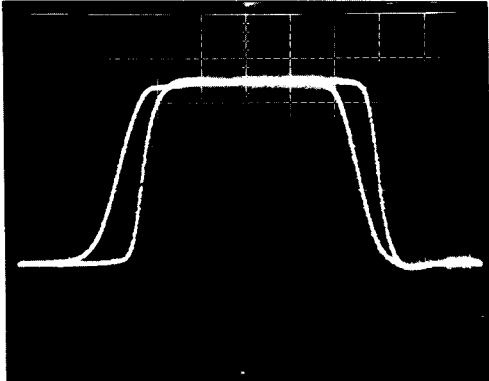
**SET/RESET WAVE FORM**  
 MB813A



MB810A  
MB811A  
MB812A  
MB813A  
MB814A

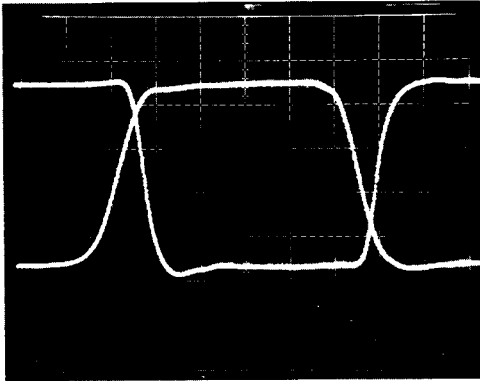
# SWITCHING CHARACTERISTICS (MB811A)

X OUTPUT



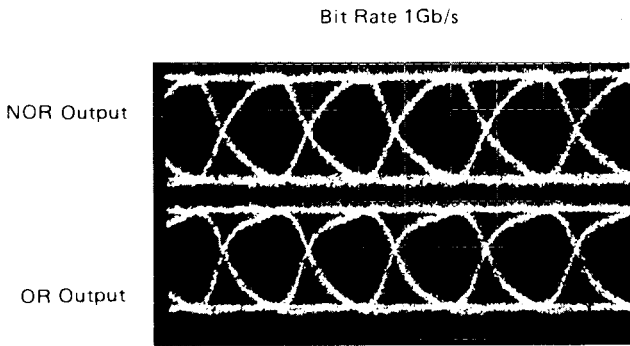
H = 1ns/div V = 200mV/div

$\bar{X}$  OUTPUT



H = 1ns/div V = 200mV/div

EYE PATTERN

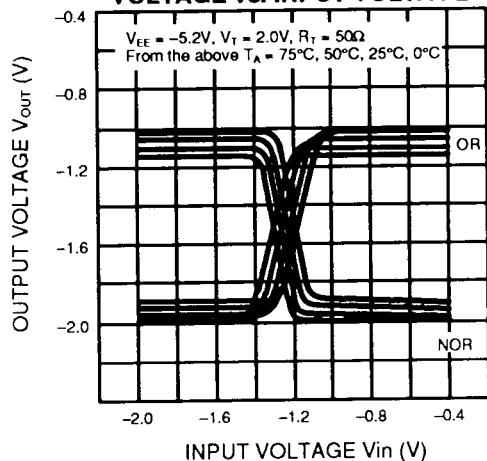


H = 500ps/div V = 400mV/div

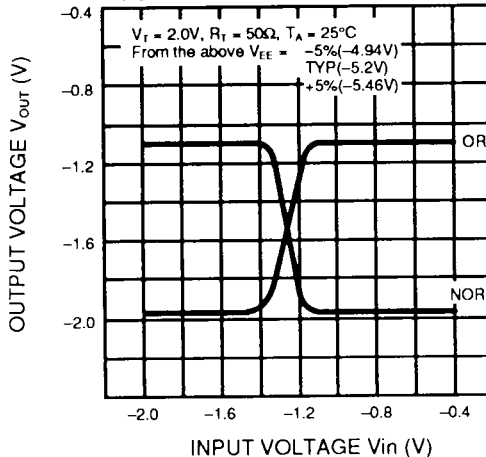


# TYPICAL CHARACTERISTICS CURVES

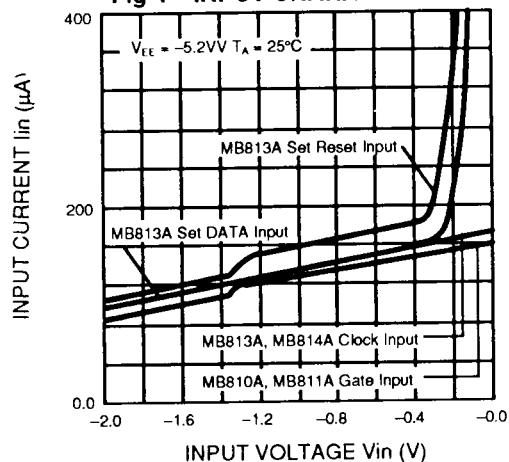
**Fig 2 – MB810A, MB811A OUTPUT VOLTAGE vs. INPUT VOLTAGE**



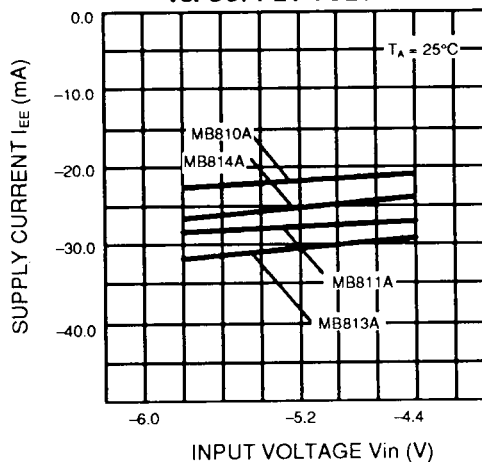
**Fig 3 – MB810A, MB811A OUTPUT VOLTAGE vs. INPUT VOLTAGE**



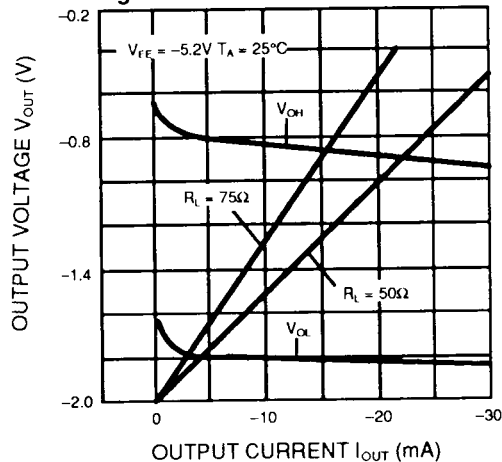
**Fig 4 – INPUT CHARACTERISTIC**



**Fig 5 – SUPPLY CURRENT vs. SUPPLY VOLTAGE**



**Fig 6 – OUTPUT CHARACTERISTIC**



## TYPICAL CHARACTERISTICS CURVES (Continued)

Fig 7 – MB810A, MB811A  
 PROPAGATION DELAY TIME  
 vs, TEMPERATURE

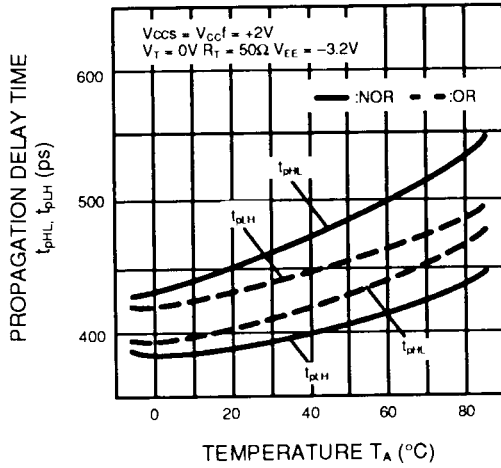
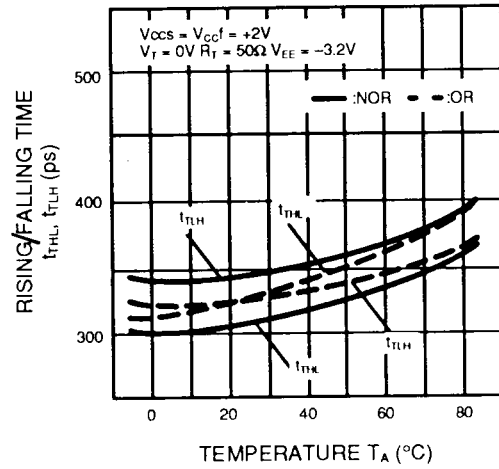
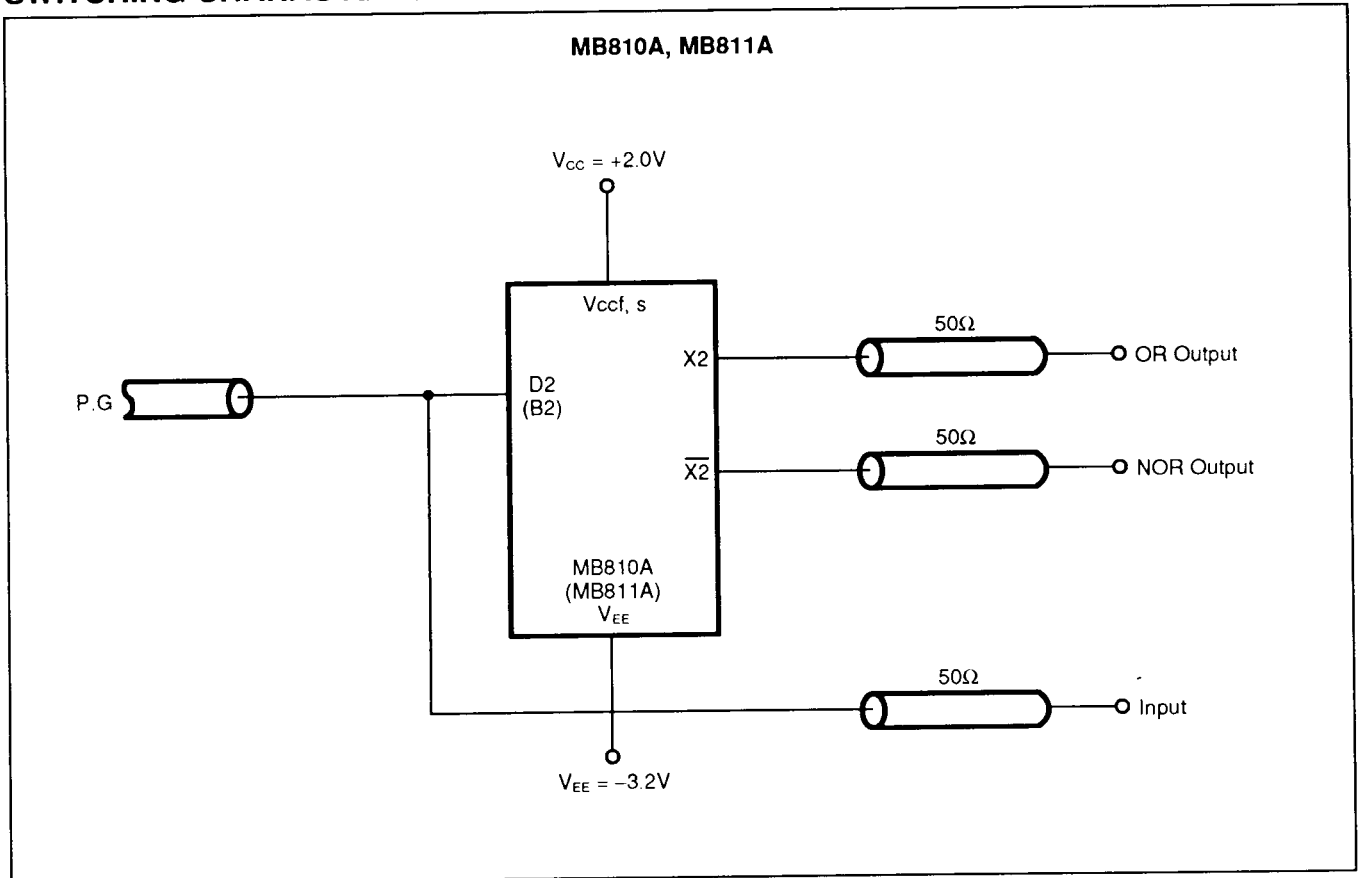


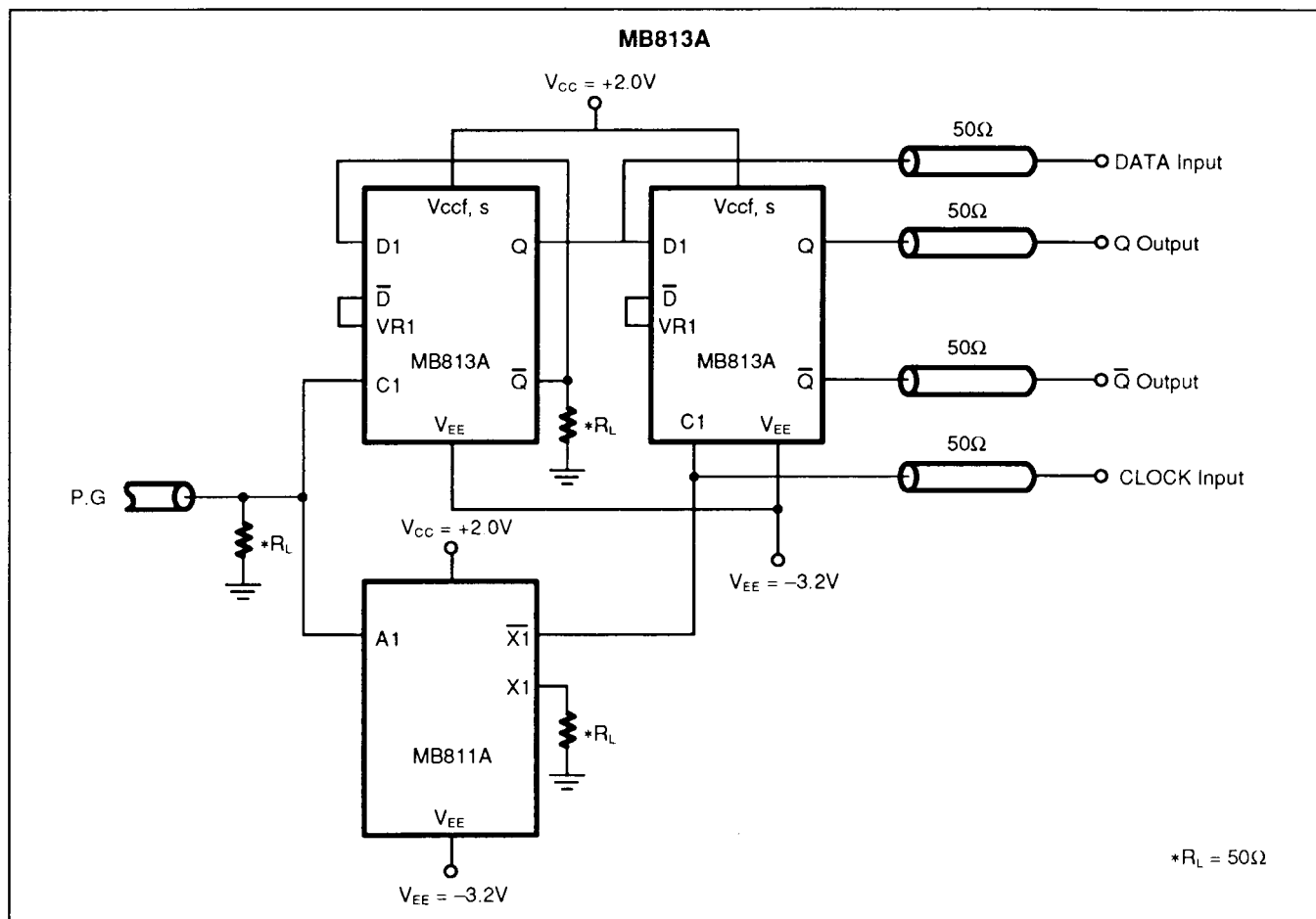
Fig 8 – MB810A, MB811A  
 RISING/FALLING TIME  
 vs, TEMPERATURE



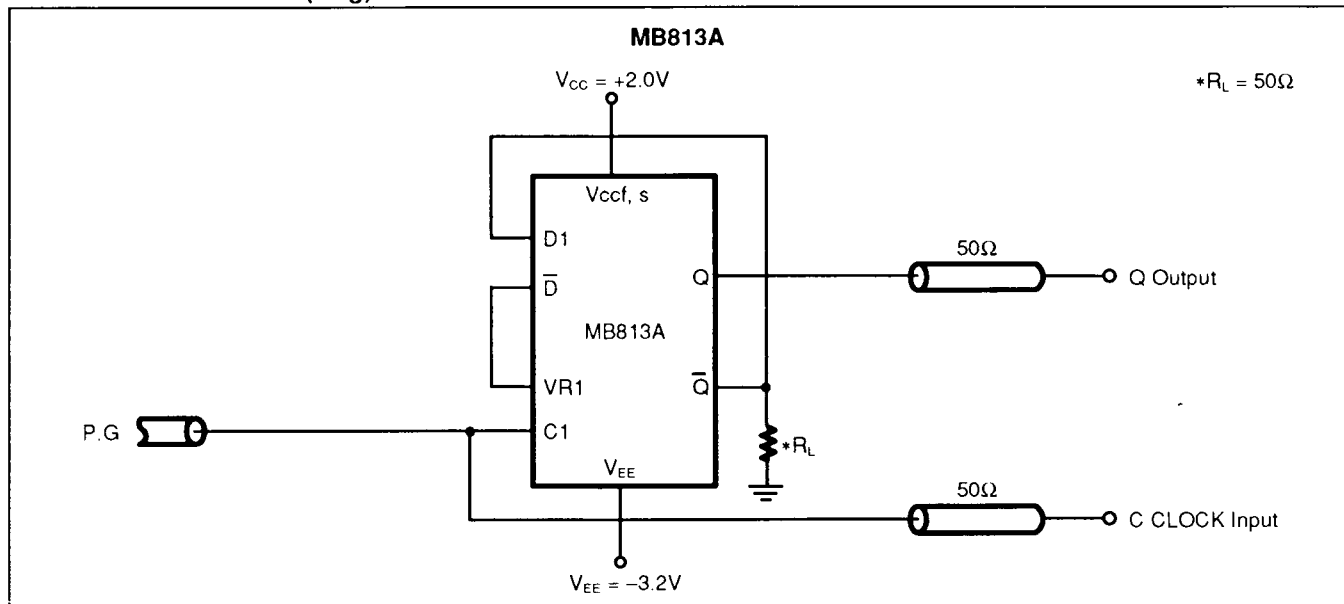
## TEST CIRCUIT SWITCHING CHARACTERISTICS



## TEST CIRCUIT (Continued)

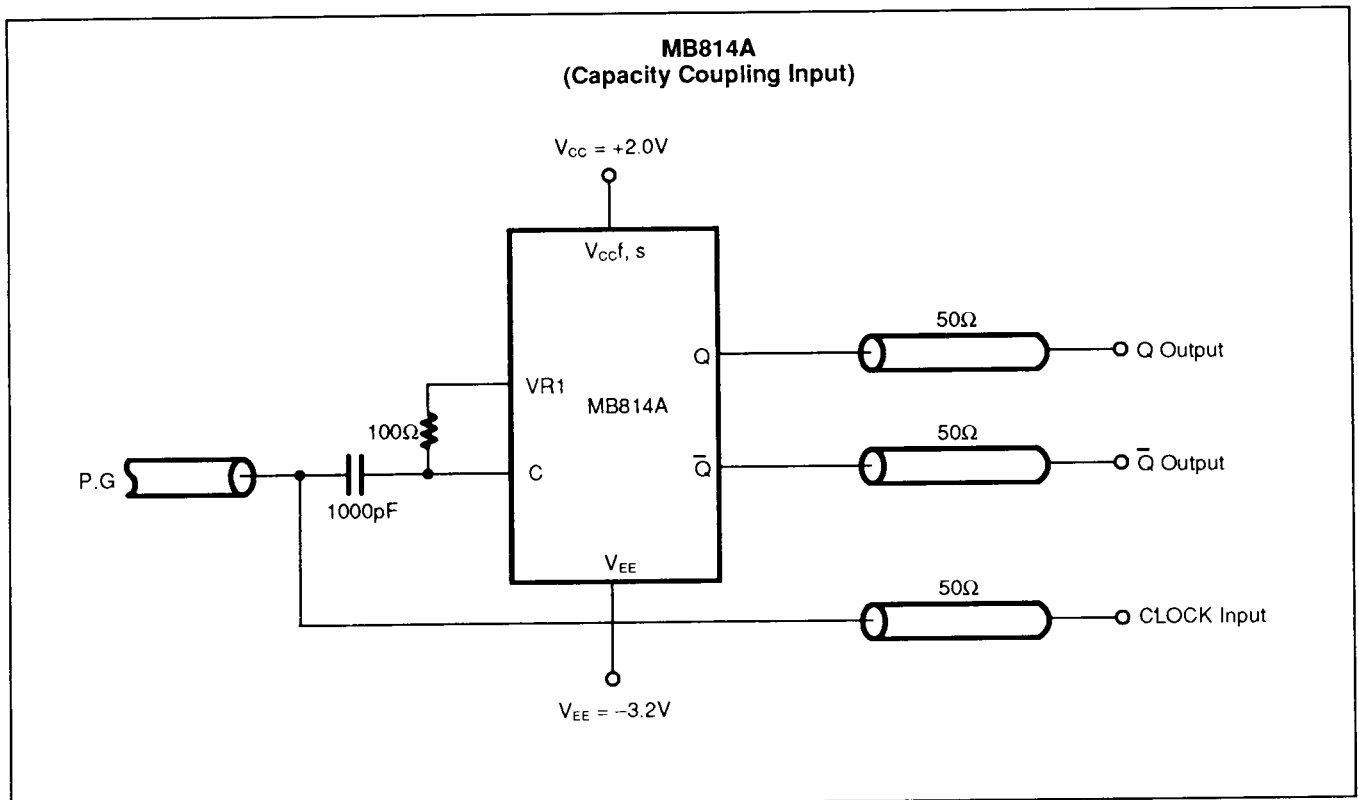
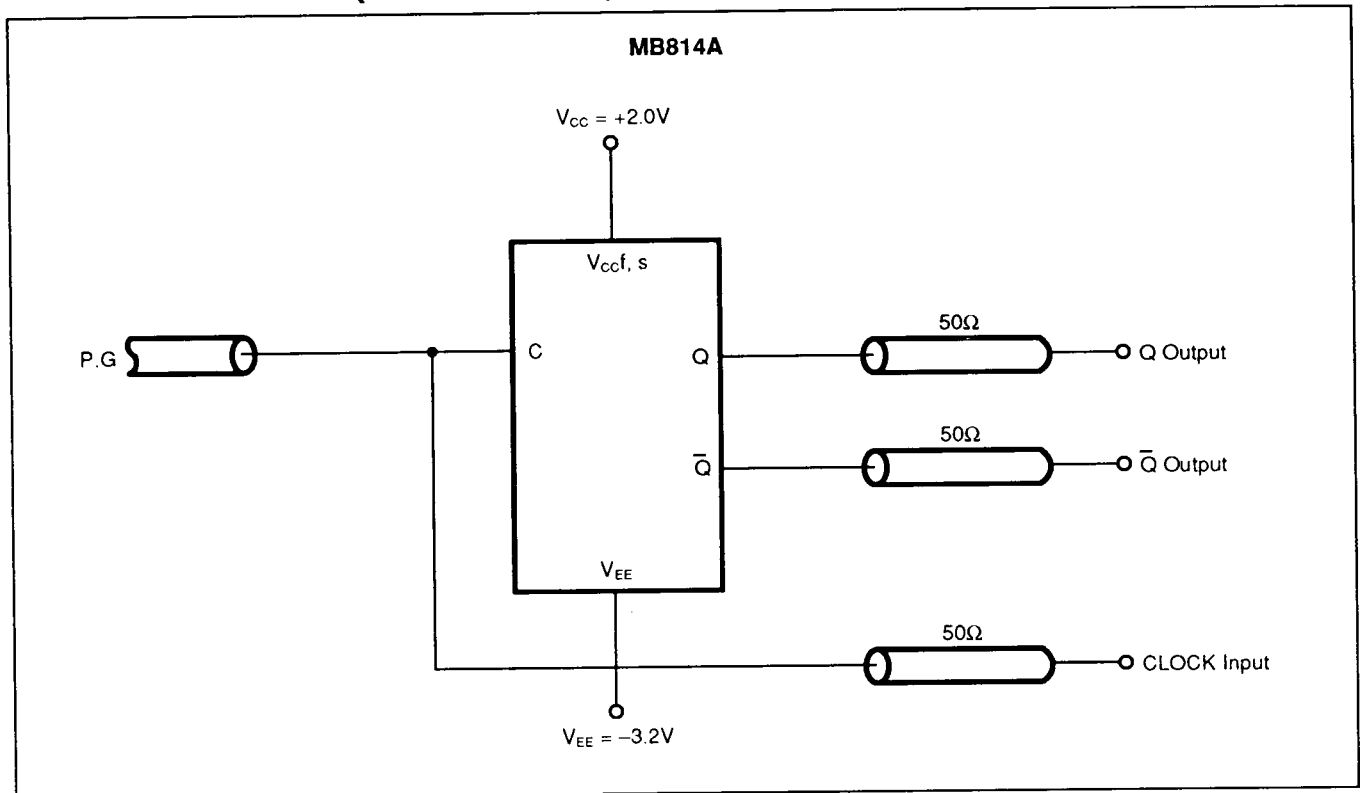


## TOGGLE FREQUENCY (ftog)



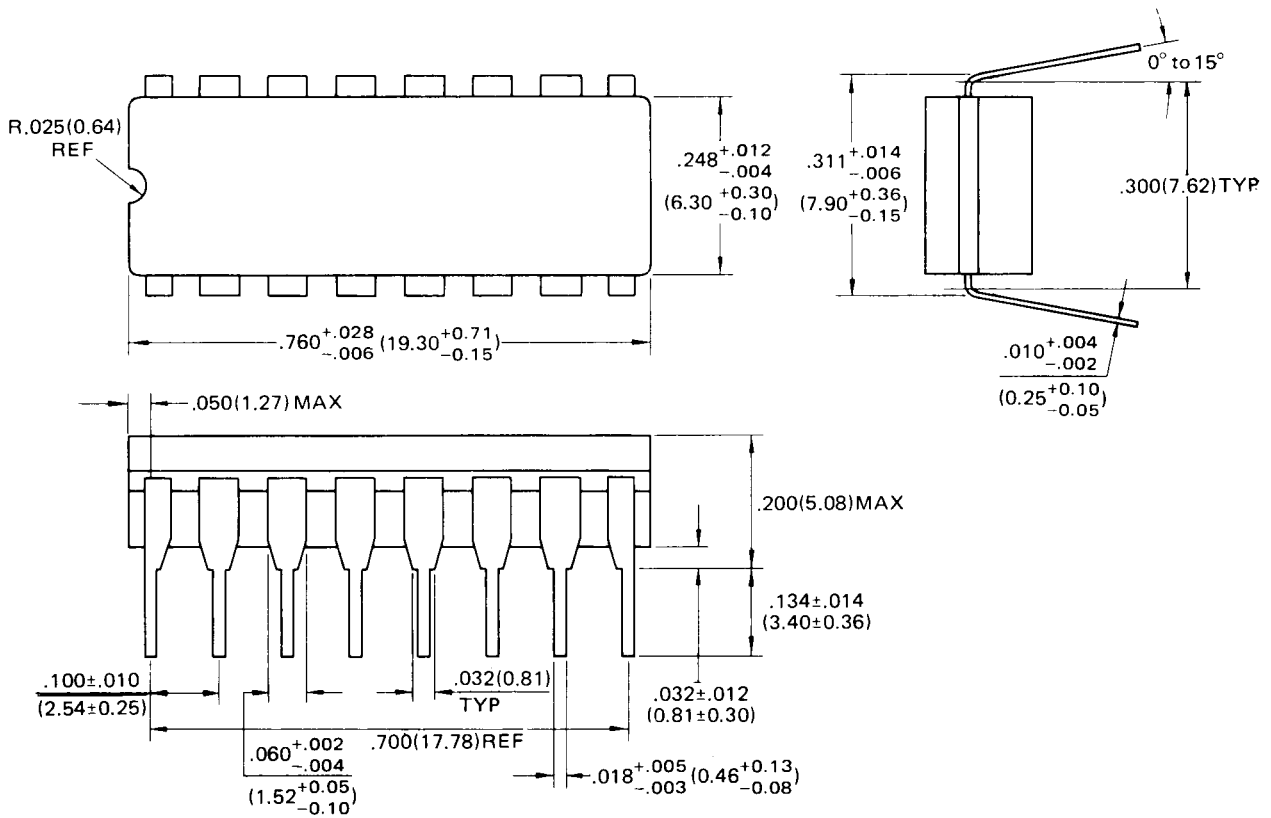
MB810A  
MB811A  
MB812A  
MB813A  
MB814A

## TEST CIRCUIT (Continued)



# PACKAGE DIMENSIONS

16-LEAD CERAMIC (CERDIP) DUAL IN-LINE PACKAGE  
 (CASE No.: DIP-16C-C01)



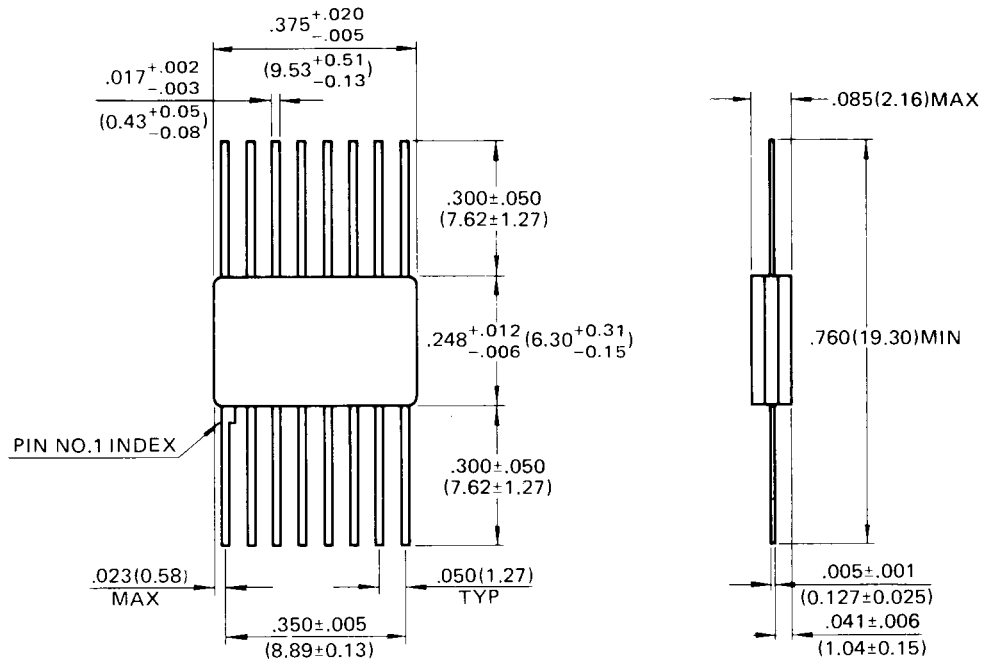
© 1988 FUJITSU LIMITED D16011S-2C

Dimensions in  
 inches (millimeters)

MB810A  
 MB811A  
 MB812A  
 MB813A  
 MB814A

## PACKAGE DIMENSIONS (Continued)

16-LEAD CERAMIC AXIAL FLAT PACKAGE  
 (CASE No.: FPT-16C-C01)



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Dimensions in inches (millimeters)

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